Application Number:	10	10029394					
		10029394					
Filing Date:	28-	28-Dec-2001					
Title of Invention:	ST	METHOD OF MANUFACTURING CODE ADDRESS MEMORY CELL BY WHICH. STACK INSULATING FILM OF AN OXIDE FILM AND A NITRIDE FILM USED AS DIELECTRIC FILM IN A FLASH MEMORY IS USED AS A GATE OXIDE FILM					
First Named Inventor/Applicant Name:	Jur	Jum Soo Kim					
Filer:	Yo	Yoon Ham/Fui Yeong KIM					
Attorney Docket Number:	12:	123034-05004731					
Filed as Large Entity							
Utility under 35 USC 111(a) Filing Fees							
Description		Fee Code	Quantity	Amount	Sub-Total in USD(\$)		
Basic Filing:					1		
Pages:							
Claims:							
Miscellaneous-Filing:							
Petition:							
Patent-Appeals-and-Interference:							
Post-Allowance-and-Post-Issuance:							

Publ. Fee- early, voluntary, or normal

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Extension-of-Time:				
Miscellaneous:				
	Total in USD (\$)			1810